

TDA7365

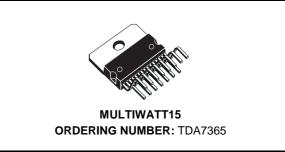
2 x 6W CAR RADIO AMPLIFIER PLUS SOLID STATE SWITCH

- OUTPUT POWER 2x6W/4Ω @14.4V, 1KHz, 10%
- SOLID STATE POWER SWITCH INCLUDED (1A @ V_{DROP} = 0.8V Typ.)
- MINIMUM EXTERNAL COMPONENT COUNT
 INTERNALLY FIXED GAIN (40dB)
 - NO BOOTSTRAP CAPACITORS
 - NO EXTERNAL COMPENSATION
- ST-BY FUNCTION (CMOS COMPATIBLE)
- MUTE FUNCTION (CMOS COMPATIBLE)
- NO AUDIBLE POP DURING MUTE/ST-BY OPERATIONS
- LOW SUPPLY SELF MUTING

PROTECTIONS

- AC AUDIO OUTPUTS SHORT CIRCUIT TO GND
- DC AUDIO OUTPUTS SHORT CIRCUIT TO GND AND TO Vs AT POWER ON
- SWITCH OUTPUT INTERNAL CURRENT LIMITATION
- OVERRATING CHIP TEMPERATURE WITH SOFT THERMAL LIMITER
- LOAD DUMP
- FORTUITOUS OPEN GND

BLOCK DIAGRAM



REVERSE BATTERY

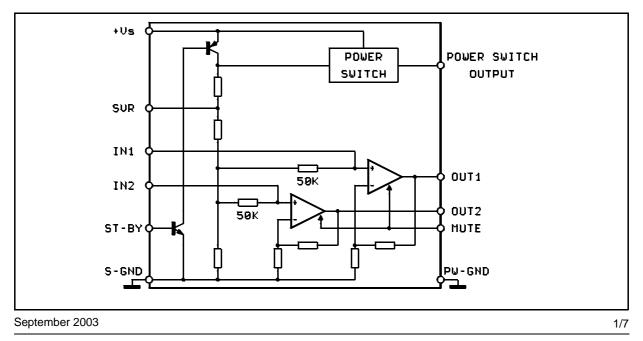
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DESCRIPTION

The TDA7365 is a new technology Dual Audio Amplifier in Multiwatt15 package especially designed for stereo car radio applications.

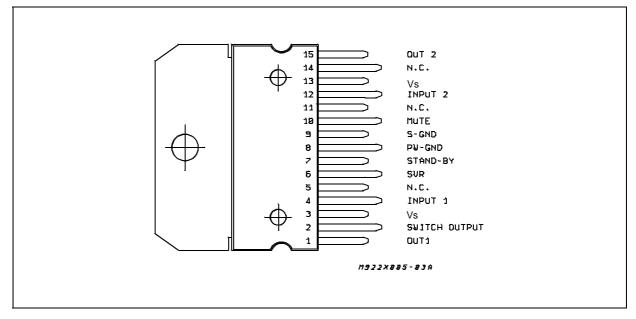
Thanks to the fully complementary output configuration the TDA7365 delivers a rail to rail voltage swing with no need of boostrap capacitors

It includes a solid state switch, enabled by a ST-BY function common to the audio section, suitable for supplying both the signal processing part of the car radio set and the lamps. As a results the power-on operation is simplified, thereby saving cost and space in the whole power section.



TDA7365

PIN CONNECTION (Top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	DC Supply Voltage	28	V
V _{OP}	Operating Supply Voltage	18	V
V _{PEAK}	Peak Supply Voltage (t = 50ms)	40	V
lo	Audio Channels Output Peak Current (not rep. t = 100µs)	4	А
lo	Audio Channels Output Peak Current (rep. f > 10Hz)	3	Α
lo	Switch Output Peak Current	(internally limited) 1.5	А
P _{tot}	Power Dissipation ($T_{case} = 85^{\circ}C$)	32	W
T _{stg} , T _j	Storage and Junction Temperature	-40 to 150	°C

THERMAL DATA

Symbol	Description		Value	Unit
R _{th j-case}	Thermal Resistance Junction-case	Max	2	°C/W



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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Range		8		18	V
l _d	Total Quiescent Drain Current	Power Switch Unloaded		80		mA
Po	Output Power	$R_L = 4\Omega$; THD = 10% each channel	5.5	6		W
		$R_L = 2\Omega$; THD = 10% each channel		9		W
d	Distortion	$P_0 = 0.1$ to 3W		0.08	0.3	%
СТ	Cross Talk	$ f = 1 kHz; R_g = 0 $ $ f = 10 kHz; R_g = 0 $	50	55 50		dB dB
R _{IN}	Input Impedance		40	50		KΩ
Gv	Voltage Gain		39	40	41	dB
Gv	Voltage Gain Match.				1	dB
EIN	Input Noise Voltage (*)	Rg = 0		1.2	5	μV
SVR	Supply Voltage Rejection	$R_g = 0$; f = 100Hz; V _r = 0.5V _{ms}	45	50		dB
ASB	Stand-by Attenuation		60	90		dB
I _{SB}	ST-BY Current Consumption				100	μΑ
V _{SB IN}	ST-BY IN Threshold Voltage				1.5	V
V _{SB OUT}	ST-BY OUT Threshold Voltage		3.5			V
V _{MIN}	MUTE IN Threshold Voltage				1.5	V
V _{M OUT}	MUTE OUT Threshold Voltage		3.5			V

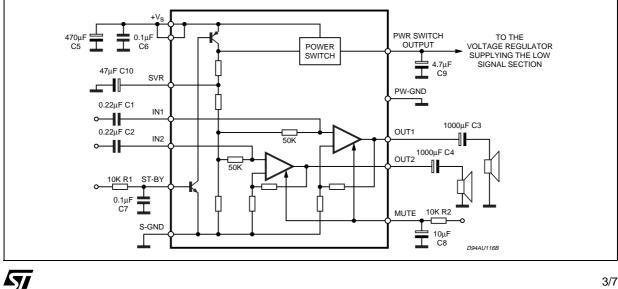
ELECTRICAL CHARACTERISTICS (Refer to the test circuit; $V_S = 14.4V$; $R_L = 4\Omega$, $T_{amb} = 25^{\circ}C$, f = 1kHz, unless otherwise specified)

POWER SWITCH CHARACTERISTICS

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{Op}	Continuous Output Current			1.2		А
VDROP	Dropout Voltage	lo = 1A			1.4	V

(*) 22Hz to 22KHz (**) A weighted

TEST AND APPLICATION CIRCUIT



TDA7365

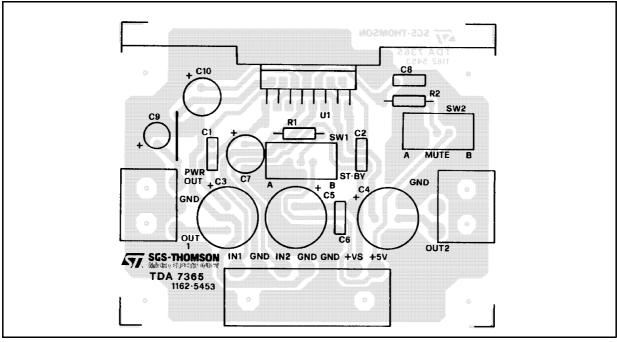


Figure 1: P.C.Board and component layout of the Test and Application Circuit 1:1 scale.

Figure 2: Quiescent Drain Current vs. Supply Voltage

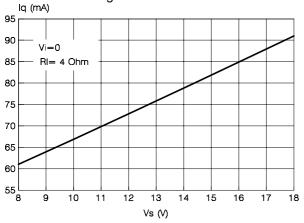
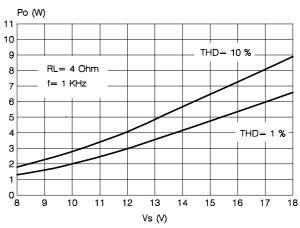
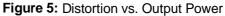
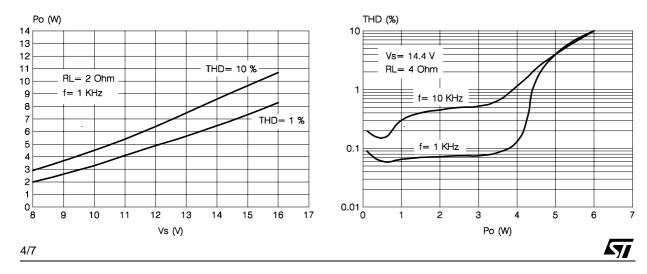


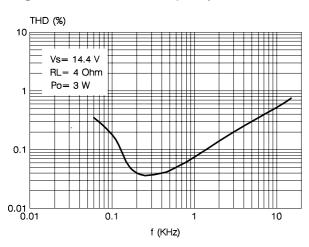


Figure 3: Output Power vs. Supply Voltage



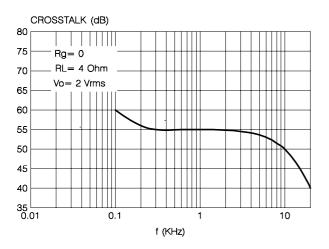






Fiigure 6: Distortion vs. Frequency

Fiigure 8: Cross-Talk vs. Frequency





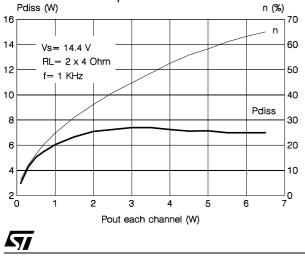


Figure 7: Supply Voltage Rejection

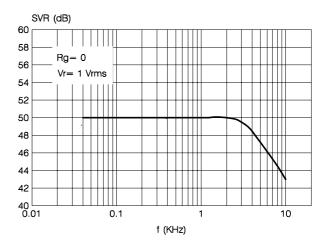
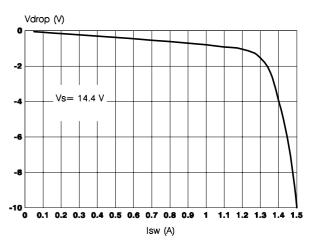
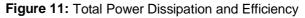
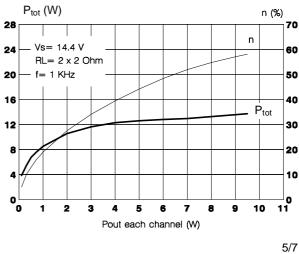


Figure 9: Switch Drop-out vs. Switch Current

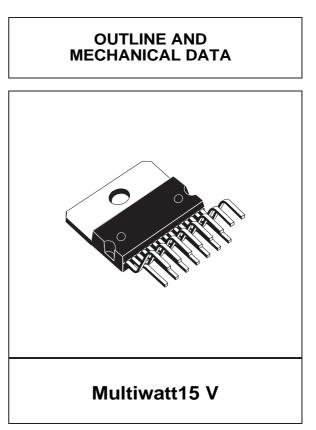


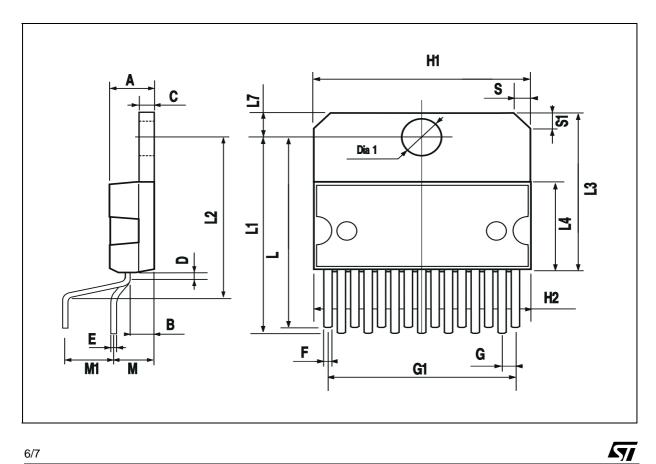




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DIM.	mm			inch			
DINI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			5			0.197	
В			2.65			0.104	
С			1.6			0.063	
D		1			0.039		
Е	0.49		0.55	0.019		0.022	
F	0.66		0.75	0.026		0.030	
G	1.02	1.27	1.52	0.040	0.050	0.060	
G1	17.53	17.78	18.03	0.690	0.700	0.710	
H1	19.6			0.772			
H2			20.2			0.795	
L	21.9	22.2	22.5	0.862	0.874	0.886	
L1	21.7	22.1	22.5	0.854	0.870	0.886	
L2	17.65		18.1	0.695		0.713	
L3	17.25	17.5	17.75	0.679	0.689	0.699	
L4	10.3	10.7	10.9	0.406	0.421	0.429	
L7	2.65		2.9	0.104		0.114	
М	4.25	4.55	4.85	0.167	0.179	0.191	
M1	4.63	5.08	5.53	0.182	0.200	0.218	
S	1.9		2.6	0.075		0.102	
S1	1.9		2.6	0.075		0.102	
Dia1	3.65		3.85	0.144		0.152	





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